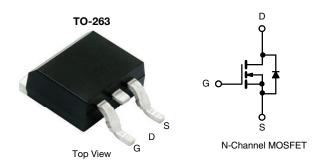


Automotive N-Channel 150 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	150				
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.052				
I _D (A)	25				
Configuration	Single				
Package	TO-263				



FEATURES

- TrenchFET® power MOSFET
- · Package with low thermal resistance
- 100 % Rg and UIS tested
- AEC-Q101 qualified ^d
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ABSOLUTE MAXIMUM RATINGS (T	$_{\rm C}$ = 25 °C, unless	otherwise noted)		
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-Source Voltage		V _{DS}	150	V	
Gate-Source Voltage		V _{GS}	± 20	V	
Continuous Drain Current	T _C = 25 °C	I_	25		
Continuous Drain Current	T _C = 125 °C	I _D	16		
Continuous Source Current (Diode Conduction) ^a		I _S	50	A	
Pulsed Drain Current ^b		I _{DM}	65		
Single Pulse Avalanche Energy L = 0.1 mH		I _{AS}	30		
Single Pulse Avalanche Current		E _{AS}	45	mJ	
Maximum Power Dissipation ^b	T _C = 25 °C	D	107	W	
Maximum Fower Dissipation -	T _C = 125 °C	P _D	35	vv	
Operating Junction and Storage Temperature Ra	nge	T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS						
PARAMETER	SYMBOL	LIMIT	UNIT			
Junction-to-Ambient	R _{thJA}	40	°C/W			
Junction-to-Case (Drain)		R _{thJC}	1.4	0/10		

Notes

a. Package limited.

b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$

c. When mounted on 1" square PCB (FR4 material).

d. Parametric verification ongoing.

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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static		1			<u> </u>	1		
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_D = 250 \mu A$		150	-	-	v	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μΑ	2.5	3	4	v	
Gate-Source Leakage	I _{GSS}	V _{DS} =	0 V, V _{GS} = ± 20 V	-	-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = 150 V	-	-	1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 150 V, T _J = 125 °C	-	-	50	μA	
		$V_{GS} = 0 V$	V _{DS} = 150 V, T _J = 175 °C	-	-	250	\neg	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	30	-	-	А	
		$V_{GS} = 10 V$	I _D = 15 A	-	0.041	0.052		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 15 A, T _J = 125 °C	-	-	0.106	Ω	
		V _{GS} = 10 V	I _D = 15 A, T _J = 175 °C	-	-	0.138	0.138	
Forward Transconductance b	9 _{fs}	V _{DS} = 15 V, I _D = 15 A		-	33	-	S	
Dynamic ^b								
Input Capacitance	C _{iss}			-	1886	2360		
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	V _{GS} = 0 V V _{DS} = 25 V, f = 1 MHz		215	270	pF	
Reverse Transfer Capacitance	C _{rss}]		-	97	125	1	
Total Gate Charge ^c	Qg			-	34	51		
Gate-Source Charge ^c	Q _{gs}	$V_{GS} = 10 V$	$V_{DS} = 75 \text{ V}, \text{ I}_{D} = 25 \text{ A}$	-	14.5	-	nC	
Gate-Drain Charge ^c	Q _{gd}			-	5.4	-		
Gate Resistance	R _g	f = 1 MHz		0.35	1.0	3.2	Ω	
Turn-On Delay Time ^c	t _{d(on)}	$V_{DD} = 75 \text{ V}, \text{ R}_{\text{L}} = 3 \Omega$ $\text{I}_{\text{D}} \cong 25 \text{ A}, \text{ V}_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$		-	11	17		
Rise Time ^c	t _r			-	21	33	ns	
Turn-Off Delay Time ^c	t _{d(off)}			-	20	30		
Fall Time ^c	t _f			-	12	20		
Source-Drain Diode Ratings and Characteristics ^b								
Pulsed Current ^a	I _{SM}			-	-	65	А	
Forward Voltage	V _{SD}	$I_{\rm F} = 20 \text{ A}, V_{\rm GS} = 0 \text{ V}$			0.85	1.5	V	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

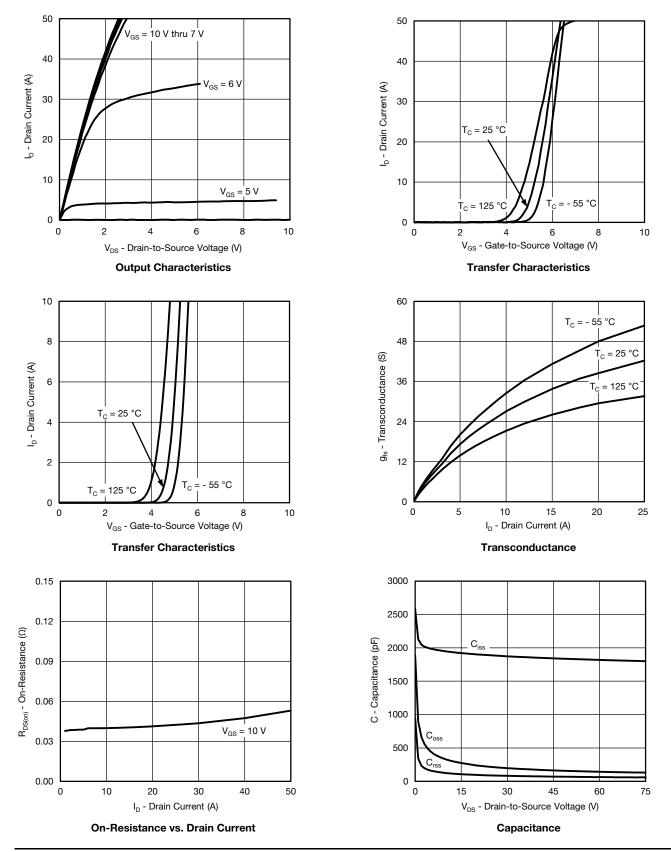
b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



S15-1819-Rev. D, 10-Aug-15

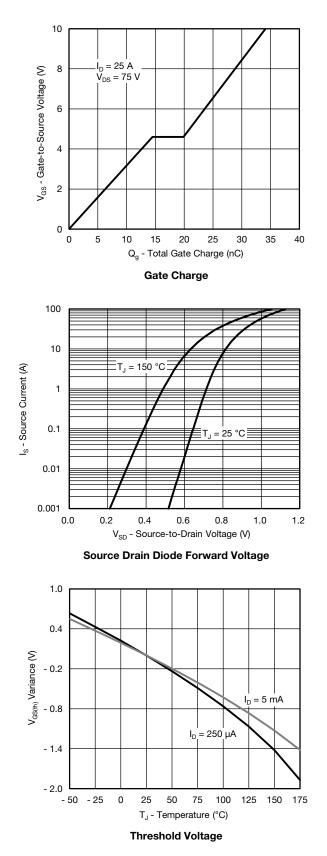
3

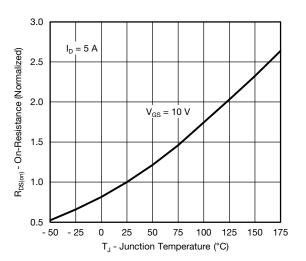
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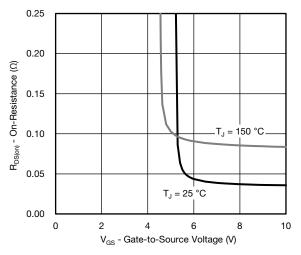


TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

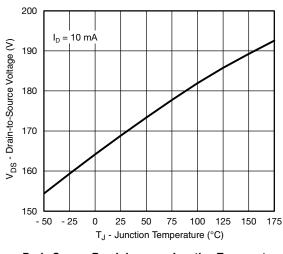




On-Resistance vs. Junction Temperature







Drain Source Breakdown vs. Junction Temperature

S15-1819-Rev. D, 10-Aug-15

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4



1

0.1

0.01

0.001

0.0001 L 10⁻⁴

Normalized Effective Transient Thermal Impedance Vishay Siliconix

THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)

10⁻³

10⁻²

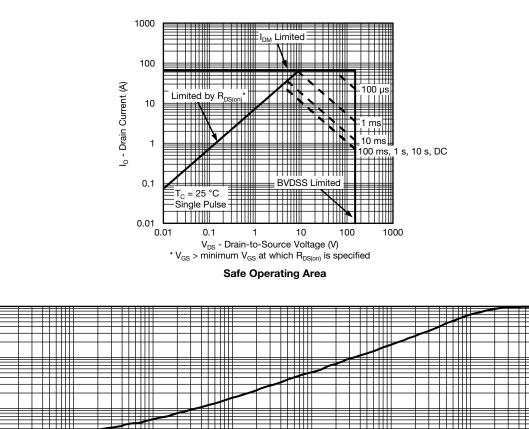
Ħ

10⁻¹

-

Square Wave Pulse Duration (s) Normalized Thermal Transient Impedance, Junction-to-Ambient

1



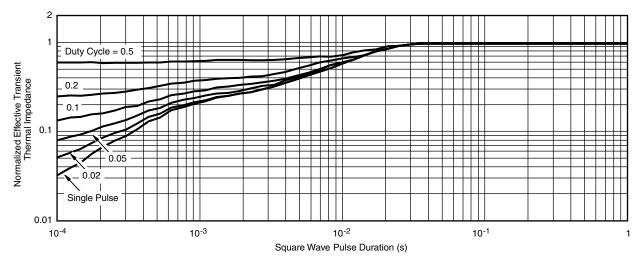
10

100

1000



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction to Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction to Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72148.



SQM25N15-52

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REVISION HISTORY^a

REVISION	DATE	DESCRIPTION OF CHANGE			
D	08-Aug-15	• R _g , C _{rss} , t _r and t _f changed			

Note

a. As of April 2014



TO-263 (D²PAK): 3-LEAD









DETAIL A (ROTATED 90°)



		INCHES		MILLIMETERS		
DIM.		MIN.	MAX.	MIN.	MAX.	
A		0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
с*	Thin lead	0.013	0.018	0.330	0.457	
C	Thick lead	0.023	0.028	0.584	0.711	
c1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
	D2	0.038	0.042	0.965	1.067	
	D3	0.045	0.055	1.143	1.397	
	D4	0.044	0.052	1.118	1.321	
	E	0.380	0.410	9.652	10.414	
	E1	0.245	-	6.223	-	
	E2	0.355	0.375	9.017	9.525	
E3		0.072	0.078	1.829	1.981	
	е	0.100 BSC		2.54 BSC		
	К	0.045	0.055	1.143	1.397	
L		0.575	0.625	14.605	15.875	
	L1	0.090	0.110	2.286	2.794	
L2		0.040	0.055	1.016	1.397	
L3		0.050	0.070	1.270	1.778	
L4		0.010 BSC		0.254 BSC		
М		-	0.002	-	0.050	
ECN: T13-0707-Rev. K, 30-Sep-13 DWG: 5843						

Notes

- 1. Plane B includes maximum features of heat sink tab and plastic. 2. No more than 25 % of L1 can fall above seating plane by
- max. 8 mils.3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB.
 - Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

This feature is for thick lead.

Revison: 30-Sep-13



RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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